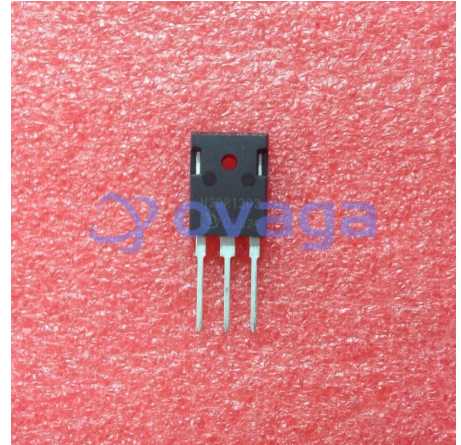


Reverse Conducting IGBT with monolithic body diode / $V_{ce} = 1200V$ / $I_c = 20A$

Manufacturers	Infineon Technologies Corporation
Package/Case	TO-247
Product Type	Discrete Semiconductors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for H20R1202 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

H20R1202 is a type of high power switching diode that is commonly used in power electronics circuits. Here are some key features and applications of the H20R1202:

Features

High voltage capability: 1200V

High current capability: 20A

Fast switching speed

Low reverse recovery time

Low forward voltage drop

Application

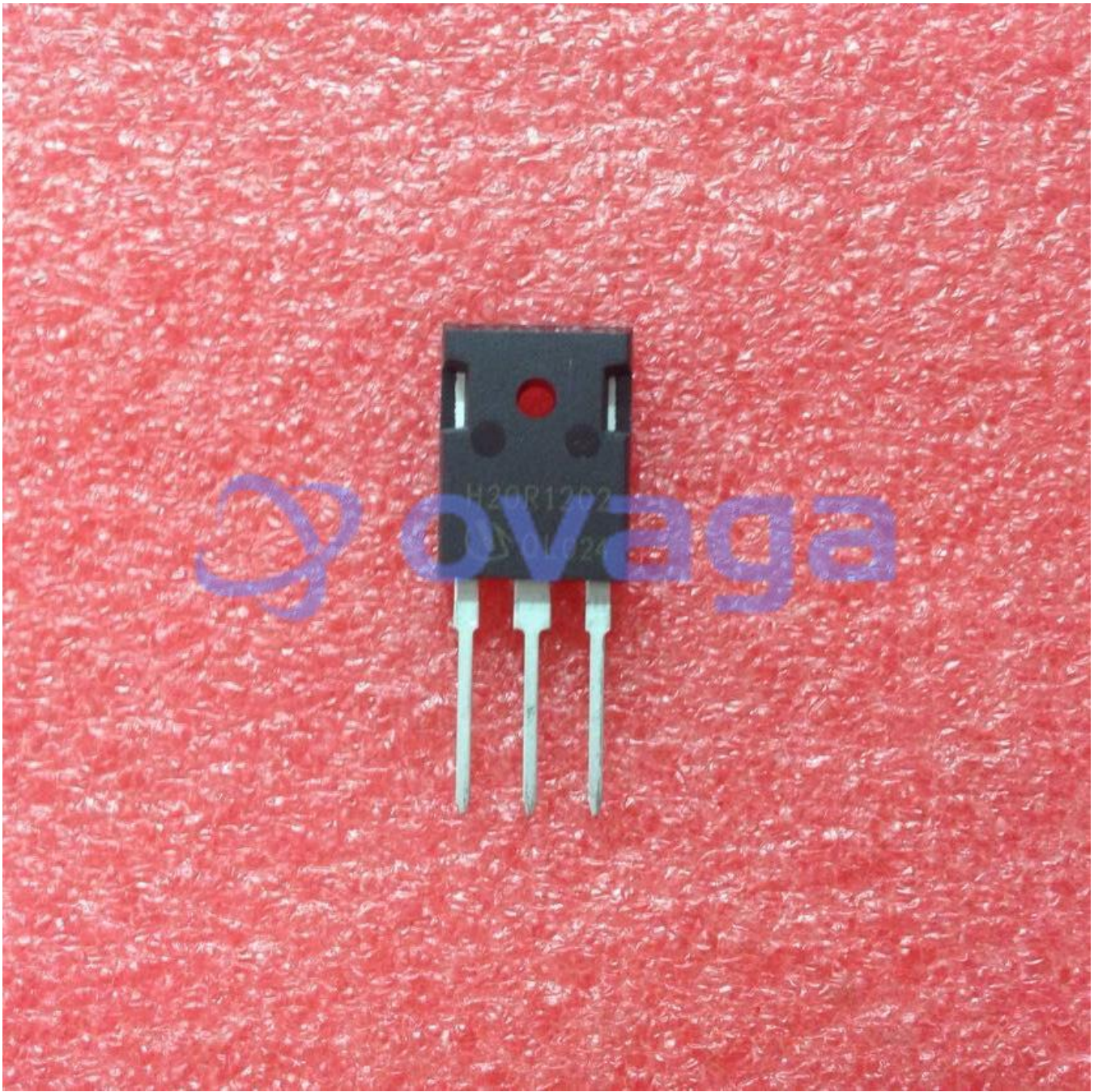
AC/DC power supplies

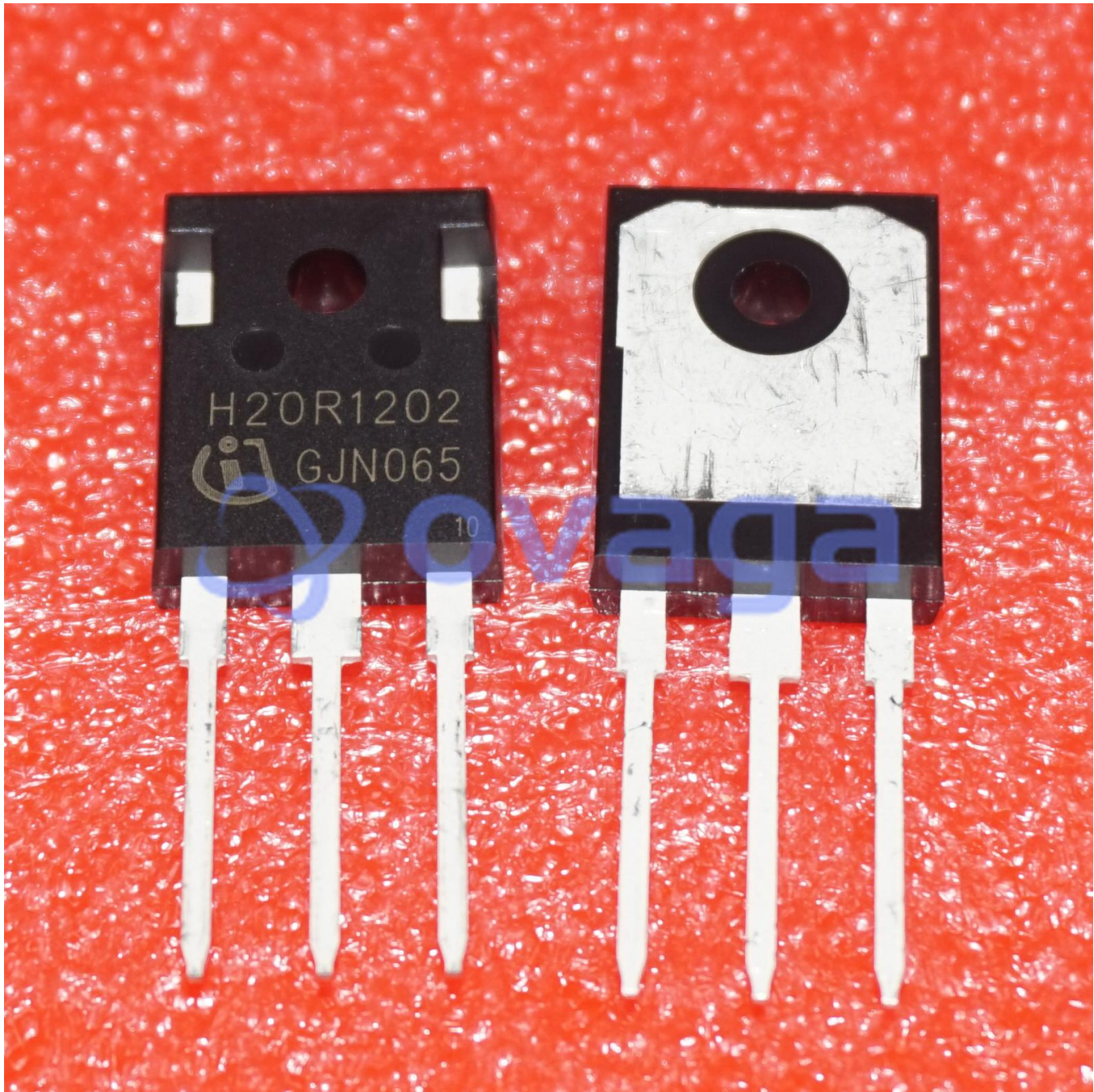
DC/DC converters

Motor control circuits

Inverter circuits

Welding equipment



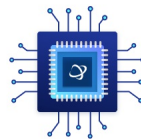


Related Products



[BTS410H2](#)

Infineon Technologies Corporation
TO-220



[IPI100N04S4-H2M](#)

Infineon Technologies Corporation



[BCX42](#)

Infineon Technologies Corporation
SOT-23



[BTS650P-E3180A](#)

Infineon Technologies Corporation
TO-263



BTS132

Infineon Technologies Corporation
TO-220



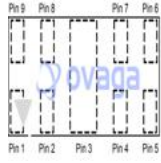
BUZ341

Infineon Technologies Corporation
TO-3P



BTS100

Infineon Technologies Corporation
TO-220



ESD5V3U4U-HDMI

Infineon Technologies Corporation
TSLP-9